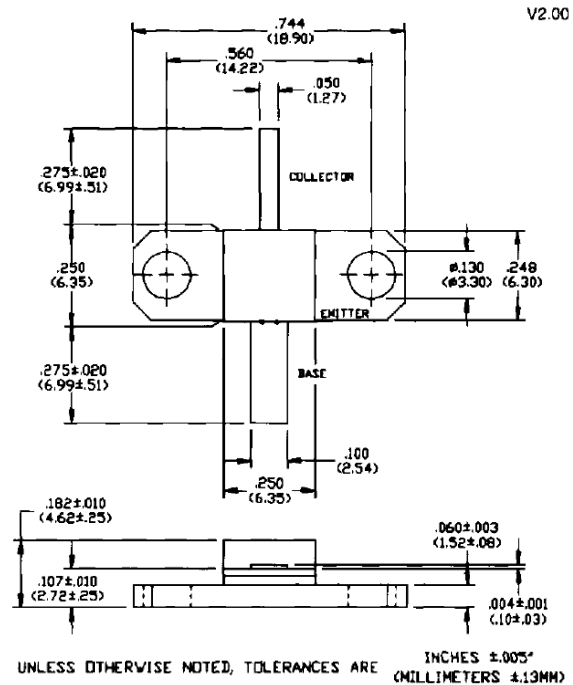


**Features**

- Designed for Cellular Base Station Applications
- Class AB: -33 dBc Typ 3rd IMD at 2 Watts PEP
- Class A: +44 dBm Typ 3rd Order Intercept Point
- Common Emitter Configuration
- Internal Input Impedance Matching
- Diffused Emitter Ballasting

**Absolute Maximum Ratings at 25°C**

Parameter	Symbol	Rating	Units
Collector-Base Voltage	$V_{CBO}$	65	V
Collector-Emitter Voltage	$V_{CES}$	65	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current	$I_C$	2.0	A
Total Power Dissipation	$P_{TOT}$	13.5	W
Junction Temperature	$T_J$	200	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C
Thermal Resistance	$\theta_{JC}$	13	°C/W

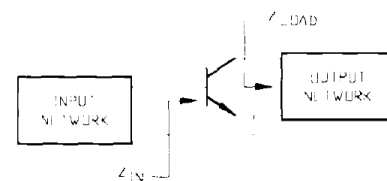


**Electrical Characteristics at 25°C**

Parameter	Symbol	Min	Max	Units	Test Conditions
Collector-Emitter Breakdown Voltage	$BV_{CES}$	65	-	V	$I_C=5\text{ mA}$
Collector-Emitter Leakage Current	$I_{CES}$	-	1.0	mA	$V_{CE}=25\text{ V}$
Collector-Emitter Breakdown Voltage	$BV_{CEO}$	22	-	V	$I_C=5\text{ mA}$
Collector-Emitter Breakdown Voltage	$BV_{CEN}$	30	-	V	$I_C=5\text{ mA}, R_{BE}=220\ \Omega$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	3.0	-	V	$I_B=5\text{ mA}$
DC Forward Current Gain	$\eta_{FE}$	15	120	-	$V_{CE}=5\text{ V}, I_C=200\text{ mA}$
Power Gain	$G_P$	10	-	dB	$V_{CC}=25\text{ V}, I_{CO}=25\text{ mA}, P_{OUT}=2.0\text{ W}, F=1.50 - 1.60\text{ GHz}$
Collector Efficiency	$\eta_C$	35	-	%	$V_{CC}=25\text{ V}, I_{CO}=25\text{ mA}, P_{OUT}=2.0\text{ W}, F=1.50 - 1.60\text{ GHz}$
Input Return Loss	RL	10	-	dB	$V_{CC}=25\text{ V}, I_{CO}=25\text{ mA}, P_{OUT}=2.0\text{ W}, F=1.50 - 1.60\text{ GHz}$
Load Mismatch Tolerance	VSWR	-	5.0:1	-	$V_{CC}=25\text{ V}, I_{CO}=25\text{ mA}, P_{OUT}=2.0\text{ W}, F=1.50 - 1.60\text{ GHz}$
3rd Order IMD	$IMD_3$	-	-32	dBc	$V_{CC}=25\text{ V}, I_{CO}=25\text{ mA}, P_{OUT}=2.0\text{ W PEP } F=1.5\text{ MHz}, \Delta F=100\text{ kHz}$

**Typical Device Impedances**

F(GHz)	$Z_{IN}(\Omega)$	$Z_{LOAD}(\Omega)$
1.45	$2.5 + j7.3$	$7.3 + j15.0$
1.50	$2.7 + j7.6$	$7.0 + j14.2$
1.60	$3.5 + j8.2$	$6.6 + j13.5$



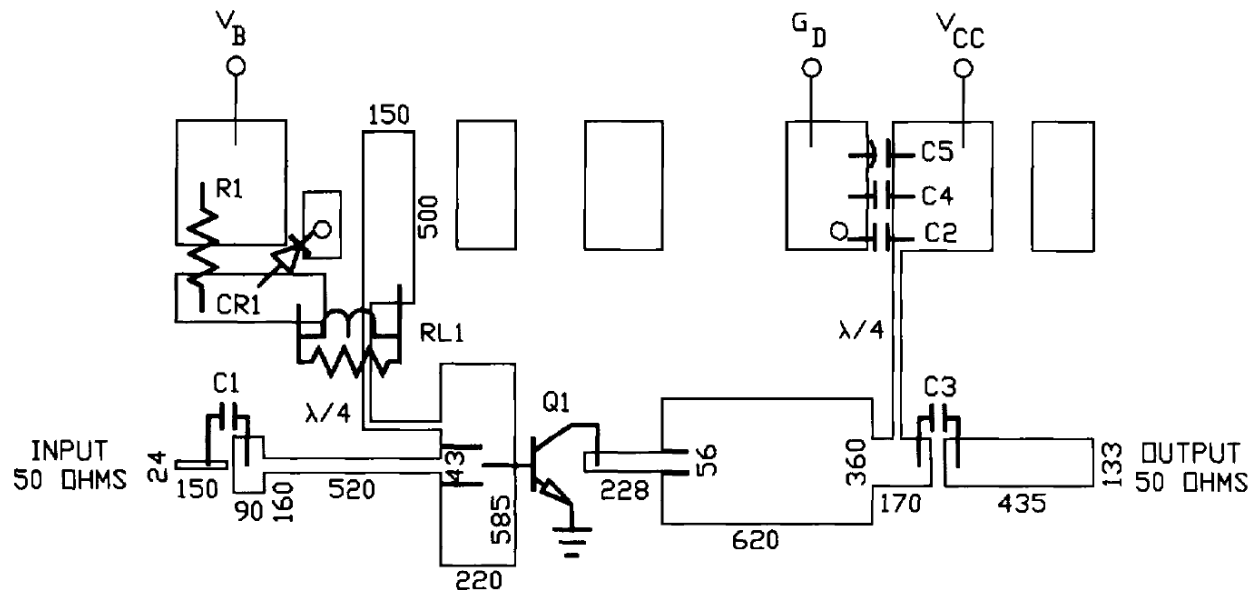
# PH1516-2

Wireless Bipolar Power Transistor, 2W

**AMERICAN  
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## RF Test Fixture



ARTWORK DIMENSIONS IN MILS

### PARTS LIST

C1	C2	C3	33 pF	ATC	SIZE A
C4			5000 pF		
C5			4.7 uF	63 VOLTS	
CR1			1N914B	DIODE	
Q1			PH1516-2		
R1			5 OHMS	1/4 WATT	
RL1			6T/ND.	24 AWG DN	3 OHM 1/4 WATT

BOARD TYPE: ROGERS 6010.5 25 THICK,  $E_R = 10.5$

Tel. 1-973-377-9566, Fax. 1-973-377-3078

133 Kings Road,  
Madison, New Jersey 07940  
United States of America

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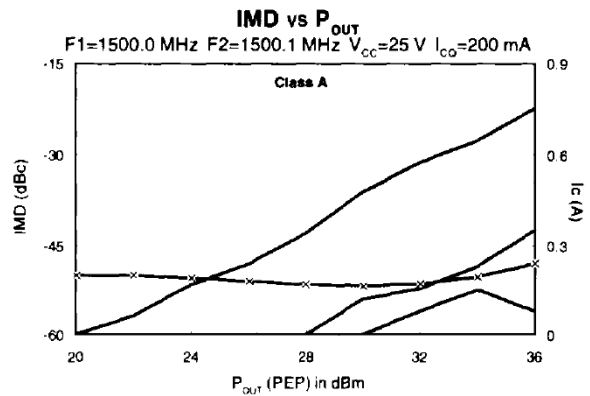
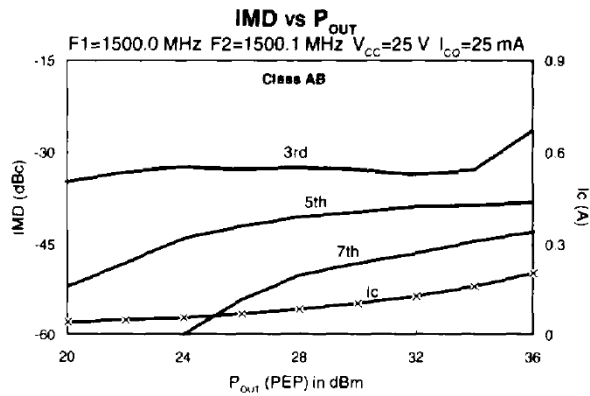
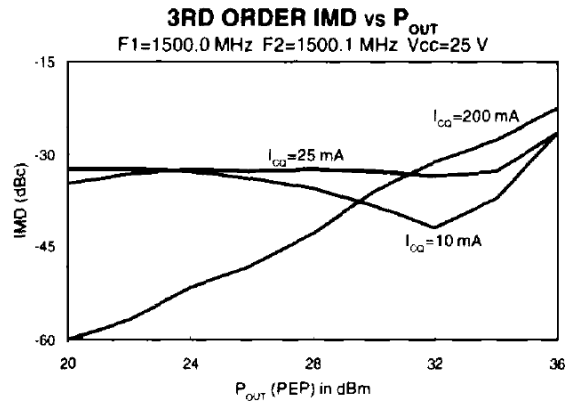
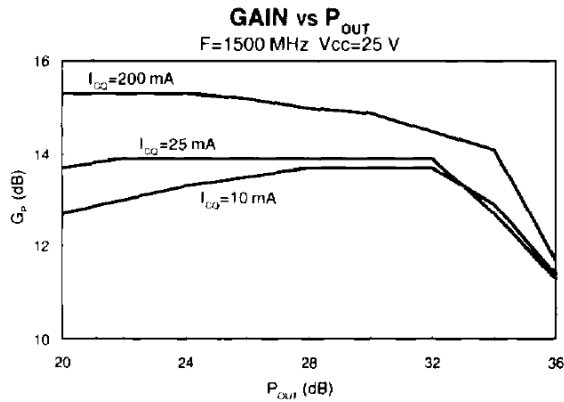
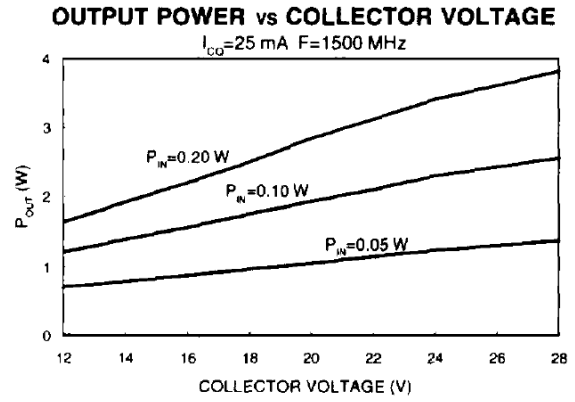
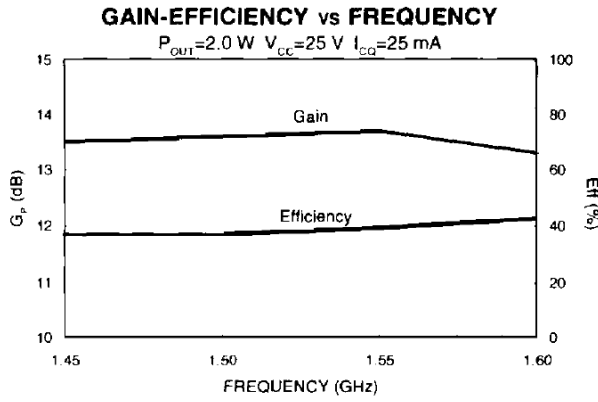
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Revised 06/2013

Aerospace Mgmt. Sys. Cert.  
AS/EN/JISQ9100:2009 Rev. C  
ISO9001:2008  
Cert No. 45325



**Typical Broadband Performance Curves**



# PH1516-2

Wireless Bipolar Power Transistor, 2W

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## Typical S-Parameters

$V_{CC}=25\text{ V}$ ,  $I_{CC}=200\text{ mA}$

f(MHz)	S11		S21		S12		S22	
	Mag	Phase	Mag	Phase	Mag	Phase	Mag	Phase
100	1.10	171.5	23.80	120.3	0.012	-7.4	0.32	-74.5
200	0.75	175.1	12.15	92.1	0.014	-4.7	0.22	-89.6
300	0.79	-177.9	7.79	81.2	0.016	-4.5	0.20	-95.7
400	0.84	-177.4	5.77	74.4	0.016	-9.8	0.23	-98.7
500	0.87	-178.5	4.65	68.4	0.017	-3.7	0.26	-100.5
600	0.89	179.8	3.96	62.6	0.018	-5.9	0.27	-101.4
700	0.89	178.3	3.49	56.7	0.018	-0.7	0.29	-104.4
800	0.91	177.4	3.08	51.1	0.019	-2.7	0.33	-103.3
900	0.91	175.4	2.89	45.4	0.017	-3.4	0.36	-111.0
1000	0.91	174.1	2.74	38.9	0.019	-0.9	0.40	-114.6
1100	0.89	171.5	2.64	28.9	0.024	-6.1	0.46	-117.3
1200	0.87	171.7	2.45	22.8	0.024	-13.6	0.53	-120.8
1300	0.86	170.8	2.35	15.7	0.023	-18.3	0.57	-122.3
1400	0.86	170.3	2.32	7.6	0.026	-21.1	0.63	-145.5
1450	0.85	170.1	2.30	3.4	0.026	-22.9	0.65	-126.2
1500	0.84	169.9	2.27	-1.2	0.025	-22.3	0.66	-127.6
1550	0.83	169.7	2.26	-6.4	0.026	-31.0	0.68	-129.1
1600	0.82	169.7	2.24	-11.5	0.030	-37.3	0.71	-131.9
1650	0.82	170.0	2.22	-16.6	0.029	-43.2	0.72	-133.6
1700	0.81	170.5	2.19	-22.4	0.027	-48.5	0.73	-137.6
1750	0.80	171.1	2.14	-28.4	0.025	-52.2	0.76	-140.1
1800	0.80	171.5	2.11	-35.5	0.026	-60.2	0.76	-143.9
1850	0.80	171.9	2.05	-40.7	0.027	-60.1	0.81	-147.5
1900	0.81	172.6	1.99	-47.4	0.024	-67.1	0.81	-150.1
2000	0.82	173.6	1.83	-60.7	0.024	-80.8	0.86	-155.5
2100	0.84	174.5	1.61	-74.0	0.020	-94.0	0.88	-160.0
2200	0.88	174.2	1.40	-84.6	0.019	-104.7	0.87	-164.5
2300	0.90	173.6	1.21	-94.7	0.016	-128.7	0.86	-168.1